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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email \& Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, \#122 Zhenhua RD., Futian, Shenzhen, China

## ASDTM

(AC Switch Family)

## OVER VOLTAGE PROTECTED

 AC POWER SWITCH
## MAIN APPLICATIONS

- AC static switching in appliance \& industrial control systems
- Washing machine with bi-rotational induction motor drive
- Induction motor drive for:
- refrigerator / freezer compressor
- air conditioning compressor


## FEATURES

- $\mathrm{V}_{\mathrm{DRM}} / \mathrm{V}_{\text {RRM }}=+/-800 \mathrm{~V}$
- Avalanche controlled device
- $\mathrm{I}_{\mathrm{T}(\mathrm{RMS})}=8 \mathrm{~A}$ with $\mathrm{T}_{\text {CASE }}=90^{\circ} \mathrm{C}$
- High noise immunity: static $\mathrm{dV} / \mathrm{dt}>750 \mathrm{~V} / \mu \mathrm{s}$
- Gate triggering current : $I_{\mathrm{GT}}<30 \mathrm{~mA}$
- Snubberless turn off commutation:
(dl/dt)c $>4.5 \mathrm{~A} / \mathrm{ms}$


## BENEFITS

■ Enables equipment to meet EN61000-4-5 standard
■ High off-state reliability with planar technology
■ Need no external overvoltage protection

- Reduces the power component count


## DESCRIPTION

The ACST8-8C belongs to the AC power switch family built around the $A S D^{\text {TM }}$ technology. This high performance device is adapted to home appliances or industrial systems and drives an induction motor up to 8A.
This ACST switch embeds a triac structure with a high voltage clamping device to absorb the inductive turn off energy and withstand line transients such as those described in the IEC61000-4-5 standards.


Table 1: Order Codes

| Part Number | Marking |
| :---: | :---: |
| ACST8-8CFP |  |
| ACST8-8CT | ACST88C |
| ACST8-8CG |  |

Figure 1: Functional Diagram


## ACST8

Table 2: Absolute Ratings (limiting values)

| Symbol | Parameter |  |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $I_{T(R M S)}$ | RMS on-state current full cycle sine wave 50 to 60 Hz | TO-220FPAB | Tcase $=90^{\circ} \mathrm{C}$ | 8 | A |
|  |  | $\begin{array}{\|l\|} \hline \text { TO-220AB / } \\ \text { D}^{2} \text { PAK } \end{array}$ | Tcase $=100^{\circ} \mathrm{C}$ | 8 |  |
| $I_{\text {TSM }}$ | Non repetitive surge peak on-state current $\mathrm{T}_{\mathrm{j}}$ initial $=25^{\circ} \mathrm{C}$, full cycle sine wave |  | $\mathrm{t}_{\mathrm{p}}=20 \mathrm{~ms}$ | 80 | A |
|  |  |  | $\mathrm{t}_{\mathrm{p}}=16.7 \mathrm{~ms}$ | 85 | A |
| $\mathrm{I}^{2} \mathrm{t}$ | Thermal constraint for fuse selection |  | $\mathrm{tp}=10 \mathrm{~ms}$ | 35 | $A^{2} s$ |
| dl/dt | Non repetitive on-state current critical rate of rise $\mathrm{I}_{\mathrm{G}}=10 \mathrm{~mA}\left(\mathrm{t}_{\mathrm{r}}<100 \mathrm{~ns}\right)$ |  | Rate period $>1 \mathrm{mn}$ | 100 | A/ $\mu \mathrm{s}$ |
| VPP | Non repetitive line peak pulse voltage |  | note 1 | 2 | kV |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature range |  |  | -40 to + 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | Operating junction temperature range |  |  | - 40 to + 125 | ${ }^{\circ} \mathrm{C}$ |
| T | Maximum lead soldering temperature during 10s |  |  | 260 | ${ }^{\circ} \mathrm{C}$ |

Note 1: according to test described by IEC61000-4-5 standard \& figure A.
Table 3: Gate Characteristics (maximum values)

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{P}_{\mathrm{G}(\mathrm{AV})}$ | Average gate power dissipation | 0.1 | W |
| $\mathrm{P}_{\mathrm{GM}}$ | Peak gate power dissipation $\left(\mathrm{t}_{\mathrm{p}}=20 \mu \mathrm{~s}\right)$ | 10 | W |
| $\mathrm{I}_{\mathrm{GM}}$ | Peak gate current $\left(\mathrm{t}_{\mathrm{p}}=20 \mu \mathrm{~s}\right)$ | 1 | A |

Table 4: Thermal Resistance

| Symbol | Parameter |  | Value | Unit |
| :---: | :--- | :--- | :---: | :---: |
| $\mathrm{R}_{\mathrm{th}(\mathrm{j}-\mathrm{a})}$ | Junction to ambient | TO-220FPAB <br> TO-220AB | 60 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\mathrm{th}(\mathrm{j}-\mathrm{a})}$ | Junction to ambien (soldered on $1 \mathrm{~cm}^{2}$ copper pad) | $\mathrm{D}^{2} \mathrm{PAK}$ | 45 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\mathrm{th}(\mathrm{j}-\mathrm{c})}$ | Junction to case for full cycle sine wave conduction | TO-220FPAB | 3.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\mathrm{th}(j-\mathrm{c})}$ | Junction to case for full cycle sine wave conduction | TO-220AB <br> $\mathrm{D}^{2} \mathrm{PAK}$ | 2.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Table 5: Parameter Description

| Parameter Symbol | Parameter description |
| :---: | :--- |
| $\mathrm{I}_{\mathrm{GT}}$ | Gate triggering current |
| $\mathrm{V}_{\mathrm{GT}}$ | Gate triggering voltage |
| $\mathrm{V}_{\mathrm{GD}}$ | Non triggering voltage |
| $\mathrm{I}_{\mathrm{H}}$ | Holding current |
| $\mathrm{I}_{\mathrm{L}}$ | Latching current |
| $\mathrm{V}_{\mathrm{TM}}$ | On state voltage |
| $\mathrm{V}_{\mathrm{TO}}$ | On state characteristic threshold voltage |
| $\mathrm{R}_{\mathrm{d}}$ | On state characteristic dynamic resistance |
| $\mathrm{I}_{\mathrm{DRM}} / \mathrm{I}_{\mathrm{RRM}}$ | Forward or reverse leakage current |
| $\mathrm{dV} / \mathrm{dt}$ | Static pin OUT voltage rise |
| $(\mathrm{dI/dt)c}$ | Turn off current rate of decay |
| $\mathrm{V}_{\mathrm{CL}}$ | Avalanche voltage at turn off |

Table 6: Electrical Characteristics per Switch
For either positive or negative polary of pin OUT voltage respect to pin COM voltage

| Symbol | Test conditions |  |  | Values | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {DRM }}$ <br> $V_{\text {RRM }}$ | Repetitive peak off-state voltage |  | MAX. | 800 | V |
| $\mathrm{I}_{\mathrm{GT}}$ | $\mathrm{V}_{\text {OUT }}=12 \mathrm{~V}$ (DC) $\mathrm{R}_{\mathrm{L}}=33 \Omega$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | MAX. | 30 | mA |
| $\mathrm{V}_{\mathrm{GT}}$ | $\mathrm{V}_{\text {OUT }}=12 \mathrm{~V}$ (DC) $\mathrm{R}_{\mathrm{L}}=33 \Omega$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | MAX. | 1.5 | V |
| $\mathrm{V}_{\mathrm{GD}}$ | $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\text {DRM }} \quad \mathrm{R}_{\mathrm{L}}=3.3 \mathrm{k} \Omega$ | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ | MIN. | 0.2 | V |
| $\mathrm{I}_{\mathrm{H}}$ | lout $=100 \mathrm{~mA}$ Gate open | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | MAX. | 40 | mA |
| IL | $\mathrm{I}_{\mathrm{G}}=20 \mathrm{~mA}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | MAX. | 70 | mA |
| $\mathrm{V}_{\text {TM }}$ | IOUT $=11 \mathrm{~A} \quad \mathrm{t}_{\mathrm{p}}=380 \mu \mathrm{~s}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | MAX. | 1.5 | V |
| $\mathrm{V}_{\text {T0 }}$ |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ | MAX. | 0.95 | V |
| $\mathrm{R}_{\mathrm{d}}$ |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ | MAX. | 50 | $\mathrm{m} \Omega$ |
| IDRM $/$ | $\begin{aligned} & V_{\text {OUT }}=V_{\text {DRM }} \\ & V_{\text {OUT }}=V_{\text {RRM }} \end{aligned}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | MAX. | 10 | $\mu \mathrm{A}$ |
| IRRM |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ | MAX. | 1 | mA |
| dV/dt | $\mathrm{V}_{\text {OUT }}=550 \mathrm{~V}$ gate open | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ | MIN. | 750 | V/us |
| (dl/dt)c | Without snubber | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ | MIN. | 4.5 | A/ms |
| $\mathrm{V}_{\text {CL }}$ | $\mathrm{I}_{\mathrm{CL}}=1 \mathrm{~mA} \quad \mathrm{t}_{\mathrm{p}}=1 \mathrm{~ms}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | TYP. | 1200 | V |

## 1. AC LINE SWITCH BASIC APPLICATION

The ACST8-8C device is especially designed to drive medium power induction motors in washing machines, refrigerators, dish washers, and tumble dryers.
Pin COM : Common drive reference, to be connected to the power line neutral
Pin G : Switch Gate input to be connected to the controller
Pin OUT : Switch Output to be connected to the load
When driven from a low voltage controller, the ACST switch is triggered with a negative gate current flowing out of the gate pin G. It can be driven by the controller through a resistor as shown on the typical application diagram. In appliance systems, the ACST8-8C switch intends to drive medium power load in ON / OFF full cycle or phase angle control mode.
Thanks to its thermal and turn-off commutation characteristics, the ACST8-8C switch is able to drive an inductive load up to 8A without a turn-off aid snubber circuit.
In washing machine or drier appliances, the tumble rotates in both directions. When using bidirectional phase shift induction motor, two switches are connected on each side of the phase shift capacitor: in steady-state operation, one switch only conducts energising the coils and defining the tumble direction.

Figure 2: Typical Application Diagram


## 2. ROBUSTNESS AGAINST FAST CAPACITOR DISCHARGE

When parasitic transients or controller mis-operation occur, the blocked switch may turn on by spurious switch firing. Since the phase shift capacitor is charged, its energy is instantaneously dissipated through the two ACSTs which can be destroyed. To prevent such a failure, a resistive inductive circuit R-L is added in series with the phase shift capacitor.
The dl/dt depends on the maximal voltage $\mathrm{V}_{\text {max }}$ of the phase shift capacitor ( 700 V on 240 V mains applications), and on the inductance L :
$\frac{d I}{d t}=\frac{v_{\text {max }}}{L}$
The total switch turn on di/dt is the sum of the di/dt created by any RC noise suppressor discharge and the dl/dt created by the motor capacitor discharge.
Since the maximal dl/dt capability at turn-on of the ACST8 is $100 \mathrm{~A} / \mathrm{hs}$, the motor capacitor di/dt is assumed to be less than $50 \mathrm{~A} / \mu \mathrm{s}$; therefore, the inductance should be $14 \mu \mathrm{H}$.
The resistor R limits the surge current through the ACST8 during the capacitor discharge according to the specified curve $\mathrm{I}_{\mathrm{TSM}}=\mathrm{f}(\mathrm{tp})$ as shown in figure 11 (to be issued), and $1.2 \Omega$ is low enough to limit the resistor dissipation (usually less than 1 W ).
Finally both the $14 \mu \mathrm{H}$ inductance and the $1.2 \Omega$ resistance provide a safety margin of two on the surge current $\mathrm{I}_{\text {TSM }}$ described in figure 11.


## 3. AC LINE TRANSIENT VOLTAGE RUGGEDNESS

The ACST8-8C switch is able to safely withstand the AC line transient voltages either by clamping the low energy spikes or by breaking over under high energy shocks.
The test circuit in figure 3 is representative of the ACST application and is used to test the ACST switch according to the IEC61000-4-5 standard conditions. Thanks to the load impedance, the ACST switch withstands voltage spikes up to 2 kV above the peak line voltage by breaking over safely. Such non repetitive testing can be done 10 times on each AC line voltage polarity.

Figure 3: Overvoltage ruggedness test circuit for resistive and inductive loads according to IEC61000-4-5 standard $R=47 \Omega, L=10 \mu H$ \& $V_{P P}=2 k V$


Figure 4: Maximum power dissipation versus RMS on-state current


Figure 6: RMS on-state current versus ambient temperature


Figure 5: RMS on-state current versus case temperature


Figure 7: Relative variation of thermal impedance versus pulse duration (TO-220FPAB)


Figure 8: Relative variation of thermal impedance versus pulse duration (TO-220AB / $D^{2}$ PAK)


Figure 10: Surge peak on-state current versus number of cycles


Figure 12: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)


Figure 9: On-state characteristics (maximum values)


Figure 11: Non repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10 ms , and corresponding value of $\mathrm{I}^{2} \mathrm{t}$


Figure 13: Relative variation of critical rate of decrease of main current versus reapplied dV/ dt (typical values)


Figure 14: Relative variation of critical rate of decrease of main current versus junction temperature


Figure 16: Surge peak on-state current versus number of cycles


Figure 15: Relative variation of static dV/dt versus junction temperature


Figure 17: Ordering Information Scheme


Figure 18: TO-220AB Package Mechanical Data

| L2 |  |  | REF. | DIMENSIONS |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Millimeters |  | Inches |  |
|  |  |  |  | Min. | Max. | Min. | Max. |
|  | $\mathrm{H} 2$ |  | A | 4.40 | 4.60 | 0.173 | 0.181 |
|  | $\xrightarrow{\text { Dia }}$ |  | B | 1.23 | 1.32 | 0.048 | 0.051 |
|  | $\sqrt{\square} \sqrt{\downarrow 5} \uparrow$ |  | D | 2.40 | 2.72 | 0.094 | 0.107 |
|  | $\square^{4}$ |  | E | 0.49 | 0.70 | 0.019 | 0.027 |
|  | L6 |  | F | 0.61 | 0.88 | 0.024 | 0.034 |
|  | - |  | F1 | 1.14 | 1.70 | 0.044 | 0.066 |
|  | F2 ${ }^{-1}$ |  | F2 | 1.14 | 1.70 | 0.044 | 0.066 |
|  |  |  | G | 4.95 | 5.15 | 0.194 | 0.202 |
|  |  |  | G1 | 2.40 | 2.70 | 0.094 | 0.106 |
|  |  |  | H2 | 10 | 10.40 | 0.393 | 0.409 |
|  |  |  | L2 |  |  | 0.6 | typ. |
|  | $\stackrel{\text { G1 }}{\rightarrow}$ |  | L4 | 13 | 14 | 0.511 | 0.551 |
|  | $\rightarrow$ |  | L5 | 2.65 | 2.95 | 0.104 | 0.116 |
|  |  |  | L6 | 15.25 | 15.75 | 0.600 | 0.620 |
|  |  |  | L7 | 6.20 | 6.60 | 0.244 | 0.259 |
|  |  |  | L9 | 3.50 | 3.93 | 0.137 | 0.154 |
|  |  |  | M |  |  | 0.10 | typ. |
|  |  |  | Diam. | 3.75 | 3.85 | 0.147 | 0.151 |

Figure 19: TO-220FPAB Package Mechanical Data


Figure 20: D²PAK Package Mechanical Data

|  | * FLAT ZONE NO LESSTHAN 2 mm |  |  | DIMENSIONS |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Millimeters |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  | Min. | Max. |
|  |  |  |  |  |  |  |  |  | A | 4.40 | 4.60 | 0.173 | 0.181 |
|  |  |  |  |  |  |  |  |  | A1 | 2.49 | 2.69 | 0.098 | 0.106 |
|  |  |  |  |  |  |  |  |  | A2 | 0.03 | 0.23 | 0.001 | 0.009 |
|  |  |  |  |  |  |  |  |  | B | 0.70 | 0.93 | 0.027 | 0.037 |
|  |  |  |  |  |  |  |  |  | B2 | 1.14 | 1.70 | 0.045 | 0.067 |
|  |  |  |  |  |  |  |  |  | C | 0.45 | 0.60 | 0.017 | 0.024 |
|  |  |  |  |  |  |  |  |  | C2 | 1.23 | 1.36 | 0.048 | 0.054 |
|  |  |  |  |  |  |  |  |  | D | 8.95 | 9.35 | 0.352 | 0.368 |
|  |  |  |  |  |  |  |  |  | E | 10.00 | 10.40 | 0.393 | 0.409 |
|  |  |  |  |  |  |  |  |  | G | 4.88 | 5.28 | 0.192 | 0.208 |
|  |  |  |  |  |  |  |  |  | L | 15.00 | 15.85 | 0.590 | 0.624 |
|  |  |  |  |  |  |  |  |  | L2 | 1.27 | 1.40 | 0.050 | 0.055 |
|  |  |  |  |  |  |  |  |  | L3 | 1.40 | 1.75 | 0.055 | 0.069 |
|  |  |  |  |  |  |  |  |  | M | 2.40 | 3.20 | 0.094 | 0.126 |
|  |  |  |  |  |  |  |  |  | R |  |  |  | typ. |

Figure 21: Foot Print Dimensions
(in millimeters)


Table 7: Ordering Information

| Part Number | Marking | Package | Weight | Base qty | Delivery mode |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ACST8-8CFP | ACST88C | TO-220FPAB | 2.4 g | 50 | Tube |
| ACST8-8CT |  | TO-220AB | 2.3 g | 50 | Tube |
| ACST8-8CG |  | $\mathrm{D}^{2} \mathrm{PAK}$ | 1.5 g | 50 | Tube |
| ACST8-8CG-TR |  |  |  | 500 | Tape \& reel |

- Epoxy meets UL94, V0

Table 8: Revision History

| Date | Revision | Description of Changes |
| :---: | :---: | :--- |
| Jan-2002 | 4 B | Last update. |
| 08-Nov-2004 | 5 | TO-220AB and D² PAK packages added. |
| $24-$ Nov-2004 | 6 | Table 6 page 3 : I GT parameter added |

## ACST8

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